Error Performance of Information Decoder for SWIPT With Integrated Receiver

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Abbreviations

- SWIPT Simultaneous Wireless Information and Power Transfer
- EH Energy Harvester
- ID Information Decoder
- QD Quadratic Detector
- ED Envelope Detector
- RX Separated Receiver
- IoT Internet of Things
- IIE-RX Integrated Information and Energy Receiver
- SISO Single-Input Single-Output
- ASK Amplitude Shift Keying
- BER Bit Error Rate
- ADC Analog to Digital Converter



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Abstract

- SWIPT can be realized by means of Integrated Receiver, where both the EH and ID operate on rectified received signal.
- Researchers investigate the effect of the non-linearity of rectifier on the error performance of the information decoder when transmitting over a Nakagami-m fading channel.
- Demonstrated through analysis and simulation, that, the low-noise error performance strongly depends on the small-signal behaviour of the rectifier.
- Approximating the rectifier by a quadratic detector yields accurate bit error rate results, whereas an over-optimistic error performance is obtained when applying the envelope detector approximation.

Introduction

- SWIPT is a promising technique for powering energy-limited information-processing devices, which are commonly used in the IoT.
- Recently, a new type of RX was proposed, namely IIE-RX, which
 rectifies the incoming signal, and subsequently splits the rectifier
 output current between the EH and ID circuits.
- Authors investigate the error performance of the ID in the IIE-RX, using biased ASK on a SISO Nakagami-m block-fading channel, with the receiver knowing the distorted ASK constellation at the rectifier output.
- The main contribution is the derivation of an analytical expression for the BER of the Maximum Likelihood(ML) detector in the low-noise regime.

SWIPT with Integrated ID and EH Receiver

- Considering a single-antenna TX sending symbols a(k) from a normalized constellation(i.e, $E[|a(k)|^2] = 1$) over a flat Nakagami-m block-fading channel to a single-antenna IIE-RX.
- As discussed, the IIE-RX rectifies the input signal and then splits up the output current between ID and EH.

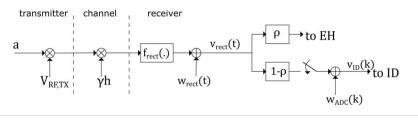


Figure: Block diagram of the Model for the IIE-RX

Symbols used in the above figure are as described,

TABLE I SYMBOL DESCRIPTION TABLE

$V_{ m RF,TX}$	TX rms voltage	ρ	current splitting factor
V_{RF}	RX rms voltage	$f_{ m rect}$	rectifier characteristic
$v_{ m ID}$	voltage at ID	$w_{ m rect}$	rectifier noise
$P_{ m EH}$	harvested power	$w_{ m ADC}$	quantization noise
$v_{ m rect}$	rectifier output	$w_{ m ID}$	total noise at ID
γh	channel gain	\mathcal{A}_M	M-ASK constellation

• During the kth symbol interval (kT, kT + T), an RF voltage $v_{RF,TX}(t)$ is applied to the TX antenna, with,

$$v_{RF,TX}(t) = \sqrt{2}|a(k)|V_{RF,TX}\cos(2\pi f_c t + \angle a(k))$$
 (1)

where |a(k)| and $\angle a(k)$ denote the magnitude and phase of a(k); the rms value of $v_{RF,TX}(t)$ in this interval equals $|a(k)|V_{RF,TX}$, making $V_{RF,TX}$ the long-term rms value.

- γh is the channel gain, such that $-20log(\gamma)$ denotes pathloss(in dB) and h is normalized fading gain.
- Assuming, $h = |h|e^{j\angle h}$ is constant over a block of K symbol intervals; |h| has a Nakagami-m distribution with $E|h^2|=1$ and $\angle h\in[0,2\pi)$, (1) can be written as,

$$v_{RF,TX}(t) = \sqrt{2}V_{RF}|h||a(k)|\cos(2\pi f_c t + \theta(k))$$
 (2)

where, $V_{RF} = \gamma V_{RF,TX}$ and $\theta(k) = \angle a(k) + \angle h$.

4 D > 4 A > 4 E > 4 E > 9 Q P

ullet The corresponding rectifier output signal $v_rect(t)$ is decomposed as ,

$$v_{rect}(t) = f_{rect}(|h||a(k)|V_{RF}) + w_{rect}(t)$$
(3)

- The function $f_{rect}(A)$ is referred to as the rectifier characteristic, which expresses the rms value A of a sinusoidal input signal.
- Considering the simple rectifier circuit from Fig.,

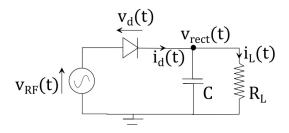


Figure: Simple Rectifier Circuit

- Here,resistive load R_L in Fig. 2 represents the parallel connection of the EH part (load $\frac{R_L}{\rho}$) and the ID part (load $\frac{R_L}{1-\rho}$) of the receiver, which draw currents $\rho \frac{V_{rect}}{R_L}$ and $(1-\rho) \frac{V_{rect}}{R_L}$, respectively.
- The current drawn by the ID part is fed to a sampler and ADC, which results in the voltage $v_{ID}(k)$,

$$v_{ID}(k) = (1 - \rho)f_{rect}(|h||a(k)|V_{RF}) + w_{ID}(k)$$
 (4)

where, $w_{ID}(k) = (1 - \rho)w_{rect}(kT) + w_{ADC}(k)$, (4) suggests that $v_{ID(k)}$ doesn't depend on the phase of data symbol a(k).

Rectifier Characteristic

• We determine the characteristic $f_{rect}(A)$ of the rectifier from above fig. by solving the differential equation,

$$C\frac{dv_{rect}}{dt} + \frac{v_{rect}}{R_L} = I_s.(e^{\frac{1}{nv_{th}}} - 1)$$
 (5)

where V_{th} is thermal voltage and the diode is characterized by the reverse saturation current I_s and ideality factor n.

• On solving using proper assumptions, we get,

$$f_{rect}(A) = \frac{1}{2} \left(\frac{1}{R_L I_s} + \frac{1}{n V_{th}} \right)^{-1} \cdot \left(\frac{A}{n V_{th}} \right)^2 \tag{6}$$

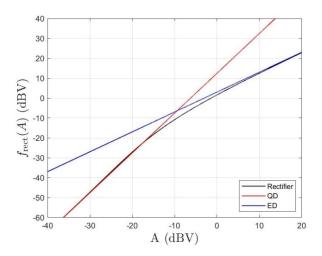


Figure: Rectifier Characteristics showing DC output voltage versus rms input voltage.

BER Analysis

- ullet Considering the transmission of uncoded symbols from biased $M ext{-}\mathsf{ASK}$ constellation A_M .
- This constellation gets distorted by the rectifier: the signal component in $v_{ID}(k)$ corresponding to $a(k) = \alpha_{\ell}$ is denoted as,

$$S_{\ell} = (1 - \rho) f_{rect}(|h|\alpha_{\ell} VRF)$$
 (7)

• For given |h|, the BER is given by,

$$BER = \frac{1}{Mlog_2 M} \sum_{i,j=0}^{M-1} n_{i,j} P_{i,j}$$
 (8)

where $n_{i,j}$ is the number of bits in which α_i and α_j differ and $P_{i,j}$ is the probability that α_i is detected when α_i is transmitted.

• After performing extensive calculation, it is obtained that,

$$BER_{avg} = C_{A_M}(m, \beta) \cdot \left(\frac{\sigma_{ID}^{2/\beta}}{V_{RF}^2}\right)^m \tag{9}$$

where m is the Nakagami parameter, β is the variable which tells whether the detector is $ED(\beta = 1)$ or $QD(\beta = 2)$ and,

$$C_{A_M}(m,\beta) = \frac{1}{M \log_2 M} \cdot \sum_{i,j=0}^{M-1} n_{i,j} D(m,\beta,i,j)$$
 (10)

• From (9), we can say, for small σ_{ID} ,

$$BER_{avg} \propto \left(\frac{\sigma_{ID}^{2/\beta}}{V_{RF}^2}\right)^m$$
 (11)

this indicates a performance advantage of ED over the rectifier for small σ_{ID} .

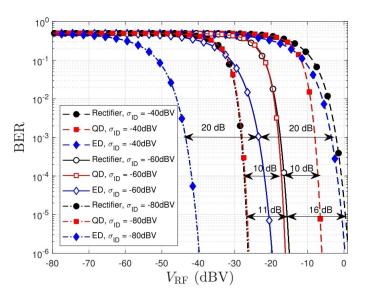


Figure: Conditional BER (|h| = 1) versus VRF (2-ASK).

Conclusion

- It is investigated the BER of the ID for SWIPT with an IIE-RX, for the uncoded transmission of biased ASK on a Nakagami-m fading channel, and presented an analytical expression for the resulting BER in the small-noise regime.
- The characteristics of the rectifier and the QD differ considerably for larger input signals, but their small-noise BER curves nearly coincide, even when the average operating point of the rectifier is outside the quadratic region.
- This behavior does not occur for a fixed channel gain, where the BER of the rectifier is closer to the BER of the ED when the rectifier operating point is outside the quadratic region.

Thank You